Preferred Device

胜特力电子(上海) 86-21-54151736

胜特力电子(深圳) 86-755-83298787

Http://www. 100y. com. tw

General Purpose Transistors 勝特力材料886-3-5753170

PNP Silicon

Features

• Pb-Free Packages are Available*



ON Semiconductor®

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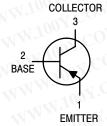
MAXIMUM RATINGS

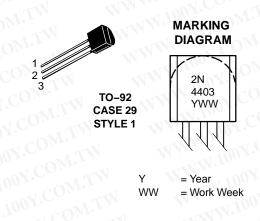
Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	40	Vdc
Collector – Base Voltage	V _{CBO}	40	Vdc
Emitter – Base Voltage	V _{EBO}	5.0	Vdc
Collector Current – Continuous	Ι _C	600	mAdc
Total Device Dissipation @ $T_A = 25^{\circ}C$ Derate above 25°C	PD	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Max	Unit
$R_{ heta JA}$	200	°C/W
R _{θJC}	83.3	°C/W
	1001.0	100Y. COM.TW





ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

2N4403 WWW.100Y.COM.TW

	ICS (T _A = 25°C unless otherwise noted) Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	NN.Im COM.	N.M.	ON	W	
Collector-Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	e (Note 1)	V _{(BR)CEO}	40	UM-	Vdc
Collector-Base Breakdown Voltage $(I_C = 0.1 \text{ mAdc}, I_E = 0)$	NWW.100Y.COM.TW W	V _{(BR)CBO}	40	WT.	Vdc
Emitter-Base Breakdown Voltage $(I_E = 0.1 \text{ mAdc}, I_C = 0)$	WWW.IOUY.COM.IW	V _{(BR)EBO}	5.0	WT.IM	Vdc
Base Cutoff Current ($V_{CE} = 35$ Vdc, $V_{EB} = 0.4$ Vdc)	WWWW.100Y.COMLTW	I _{BEV}	100 <u>7.C</u>	0.1	μAdc
Collector Cutoff Current (V _{CE} = 35 Vdc, V _{EB} = 0.4 Vdc)	勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736	I _{CEX}	N 100Y	0.1	μAdc
ON CHARACTERISTICS	胜特力电子(深圳) 86-755-83298787	MM	100	1.Com	WT
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = 0.1 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_{C} = 1.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_{C} = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_{C} = 150 \text{ mAdc}, V_{CE} = 2.0 \text{ Vdc}) (I_{C} = 500 \text{ mAdc}, V_{CE} = 2.0 \text{ Vdc}) (I_{C} = 500 \text{ mAdc}, V_{CE} = 2.0 \text{ Vdc}) \end{array} $		h _{FE}	30 60 100 100 20	- - 300 -	M.TW M.TW OM.TV
$\label{eq:collector} \begin{split} & \text{Collector-Emitter Saturation Voltage} \\ & (I_{C} = 150 \text{ mAdc}, I_{B} = 15 \text{ mAdc}) \\ & (I_{C} = 500 \text{ mAdc}, I_{B} = 50 \text{ mAdc}) \end{split}$	e (Note 1)	V _{CE(sat)}	W VIZW	0.4 0.75	Vdc
Base – Emitter Saturation Voltage (N ($I_C = 150$ mAdc, $I_B = 15$ mAdc) ($I_C = 500$ mAdc, $I_B = 50$ mAdc)	ote 1)	V _{BE(sat)}	0.75	0.95 1.3	Vdc
SMALL-SIGNAL CHARACTERISTI	CS	M.T.N		1.1	
Current-Gain - Bandwidth Product	(I _C = 20 mAdc, V _{CE} = 10 Vdc, f = 100 MHz)	f _T	200	- 1	MHz
Collector-Base Capacitance (V _{CB} =	10 Vdc, I _E = 0, f = 1.0 MHz)	C _{cb}		8.5	pF
Emitter-Base Capacitance (V _{EB} = 0	5 Vdc, I _C = 0, f = 1.0 MHz)	C _{eb}	_	30	pF
Input Impedance (I _C = 1.0 mAdc, V _C	_E = 10 Vdc, f = 1.0 kHz)	h _{ie}	🔨 1.5 k	15 k	ohms
Voltage Feedback Ratio (I _C = 1.0 m/	Ndc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{re}	0.1	8.0	X 10 ⁻⁴
Small–Signal Current Gain (I _C = 1.0	mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{fe}	60	500	1111-100
Output Admittance (I _C = 1.0 mAdc, V	/ _{CE} = 10 Vdc, f = 1.0 kHz)	h _{oe}	1.0	100	μmhos
SWITCHING CHARACTERISTICS	100X.CO.M.TW WWW.WI	001.00	1.1.1	V	N.I.
Delay Time	= 30 Vdc, V _{BE} = +2.0 Vdc,	td	WEIN	15	ns
	50 mAdc, $I_{B1} = 15$ mAdc)	tr .	WT-TV	20	ns
Storage Time (V _{CC} :	= 30 Vdc, I _C = 150 mAdc,	ts	TT TO	225	ns
	$5 \text{ mA}, \text{ I}_{B2} = 15 \text{ mA})$	t _f	-07,-,-	30	ns

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%. WWW.100Y.COM.TW WWW.100Y.

ORDERING INFORMATION

Device	Package	Shipping [†]
2N4403	TO-92	5,000 Units / Box
2N4403G	TO-92 (Pb-Free)	5,000 Units / Box
2N4403RL	TO-92	2,000 / Tape & Reel
2N4403RLRA	TO-92	2,000 / Tape & Reel
2N4403RLRAG	TO-92 (Pb-Free)	2,000 / Tape & Reel
2N4403RLRM	TO-92	2,000 / Ammo Pack
2N4403RLRP	TO-92	2,000 / Ammo Pack
2N4403RLRPG	TO-92 (Pb-Free)	2,000 / Ammo Pack
2N4403ZL1	TO-92	2,000 / Ammo Pack

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

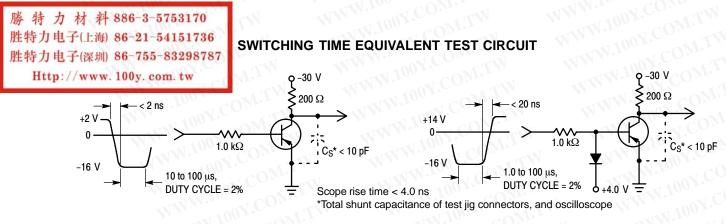
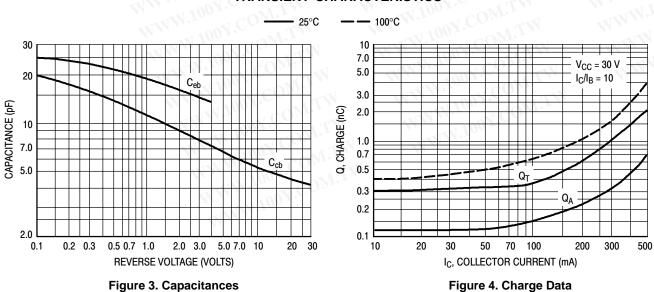
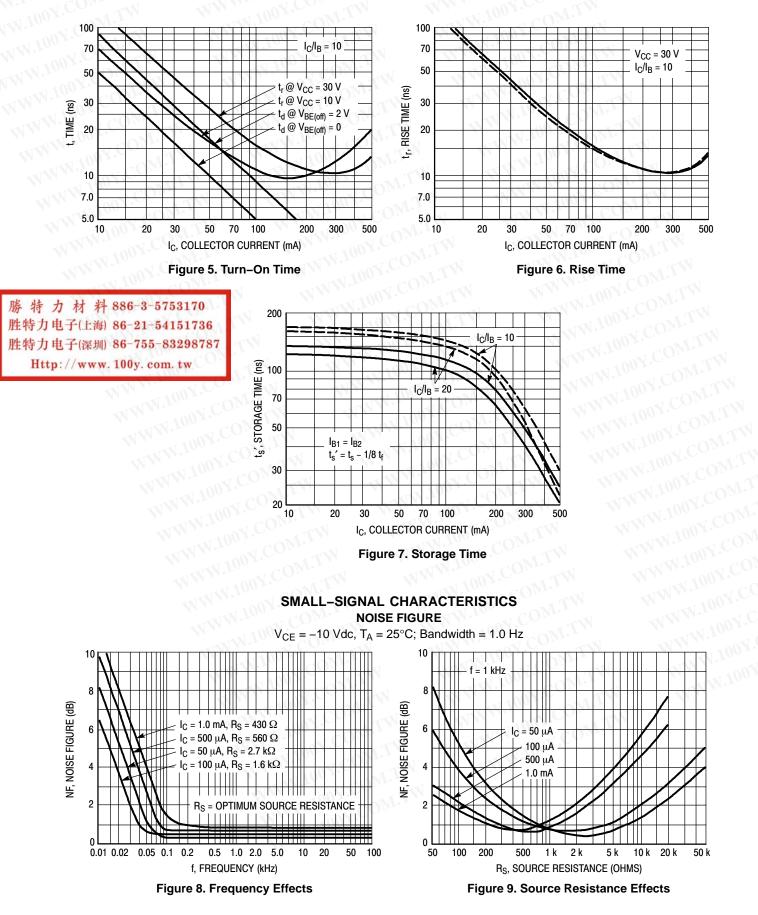


Figure 1. Turn-On Time

Figure 2. Turn-Off Time



TRANSIENT CHARACTERISTICS



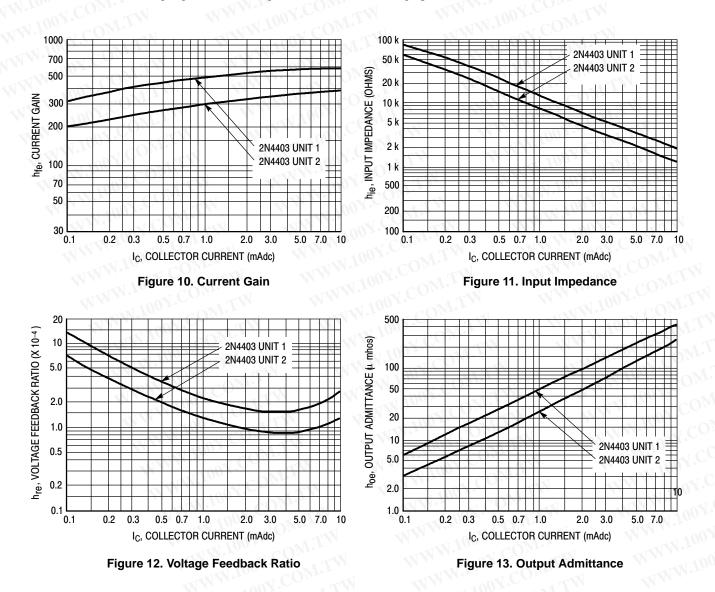
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2N4403

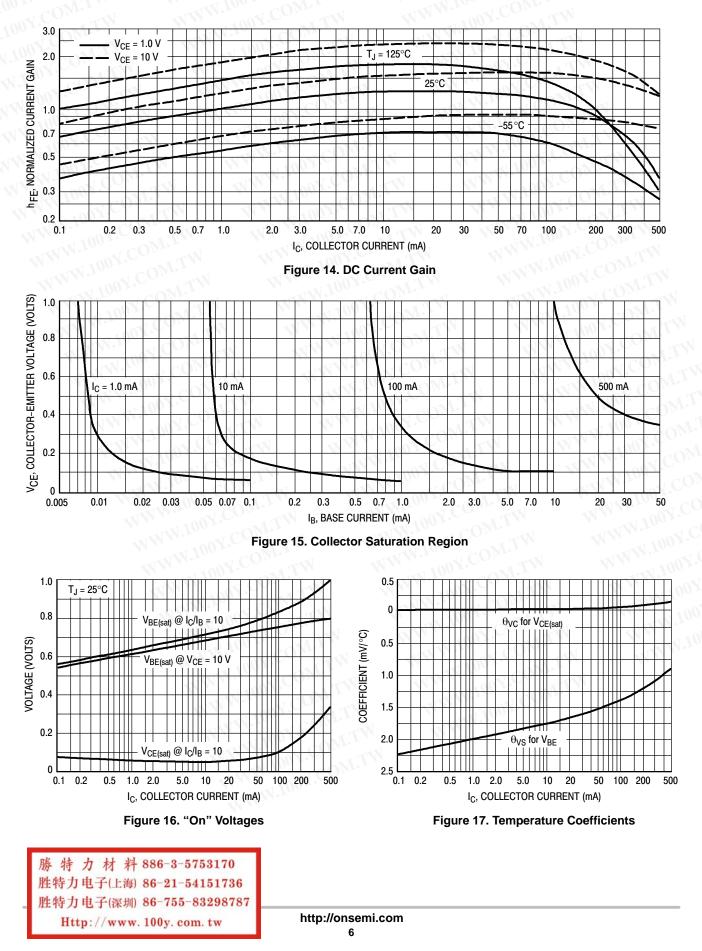
h PARAMETERS V_{CE} = −10 Vdc, f = 1.0 kHz, T_A = 25°C

This group of graphs illustrates the relationship between h_{fe} and other "h" parameters for this series of transistors. To obtain these curves, a high-gain and a low-gain unit were

selected from the 2N4403 lines, and the same units were used to develop the correspondingly–numbered curves on each graph.



100Y.COM.T STATIC CHARACTERISTICS



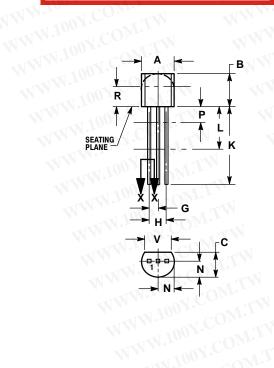
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胜特力电子(深圳) 86	-755-83298787
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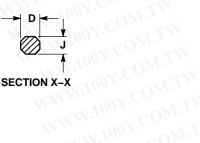
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WWW.100Y.COM.TW 100X.COM.T WW.100Y.COM.TW WWW.100Y.COM.TW PACKAGE DIMENSIONS

TO-92 **TO-226AA** CASE 29-11 **ISSUE AL**

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- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- T14.30M, 1962. CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND 2. 3.
- 4. BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
Κ	0.500	1	12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ	- 22	0.100		2.54
R	0.115		2.93	
V	0.135	1.11	3.43	-

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